Advanced Micro

Devices

PAL20R8 Family

24-Pin TTL Programmable Array Logic

DISTINCTIVE CHARACTERISTICS

- As fast as 5 ns maximum propagation delay
- Popular 24-pin architectures: 20L8, 20R8, 20R6. 20R4
- Programmable replacement for high-speed TTL logic
- Power-up reset for initialization
- Extensive third-party software and programmer support through FusionPLD partners
- 24-pin SKINNYDIP and 28-pin PLCC packages save space

GENERAL DESCRIPTION

The PAL20R8 Family (PAL20L8, PAL20R8, PAL20R6, PAL20R4) includes the PAL20R8-5 Series which is ideal for high-performance applications. The PAL20R8 Family is provided in the standard 24-pin DIP and 28-pin PLCC pinouts.

The devices provide user programmable logic for replacing conventional SSI/LSI gates and flip-flops at a reduced chip cost.

The family allows the systems engineer to implement the design on-chip, by opening fuse links to configure AND and OR gates within the device, according to the desired logic function. Complex interconnections between gates, which previously required time-consuming layout, are lifted from the PC board and placed on silicon, where they can be easily modified during prototyping or production.

The PAL device implements the familiar Boolean logic transfer function, the sum of products. The PAL device is a programmable AND array driving a fixed OR array. The AND array is programmed to create custom product terms, while the OR array sums selected terms at the outputs.

In addition, the PAL device provides the following options:

- Variable input/output pin ratio
- Programmable three-state outputs
- Registers with feedback

Product terms with all connections opened assume the logical HIGH state; product terms connected to both true and complement of any single input assume the logical LOW state. Registers consist of D-type flip-flops that are loaded on the LOW-to-HIGH transition of the clock. Unused input pins should be tied to Vcc or GND.

AMD's FusionPLD program allows PAL20R8 Family designs to be implemented using a wide variety of popular industry-standard design tools. By working closely with the FusionPLD partners, AMD certifies that the tools provide accurate, quality support. By ensuring that third-party tools are available, costs are lowered because a designer does not have to buy a complete set of new tools for each device. The FusionPLD program also greatly reduces design time since a designer can use a tool that is already installed and familiar. Please refer to the PLD Software Reference Guide for certified development systems and the Programmer Reference Guide for approved programmers.

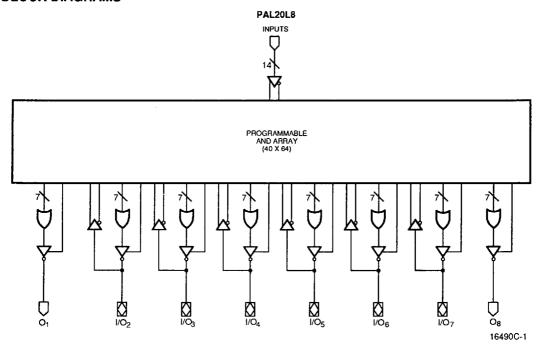
PRODUCT SELECTOR GUIDE

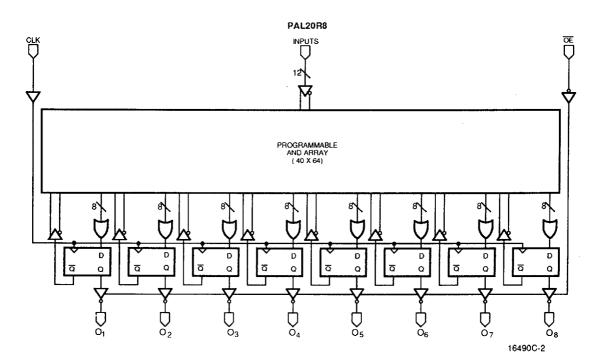
Device	Dedicated Inputs	Outputs	Product Terms/Output	Feedback	Enable
PAL20L8	14	6 comb. 2 comb.	7 7	I/O -	prog. prog.
PAL20R8	12	8 reg.	8	reg.	pin
PAL20R6	12	6 reg. 2 comb.	8 7	reg. I/O	pin prog.
PAL20R4	12	4 reg. 4 comb.	8 7	reg. I/O	pin prog.

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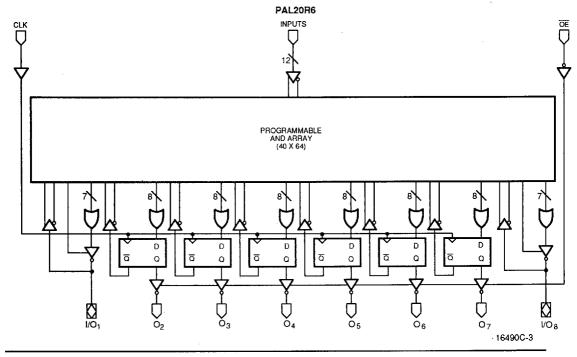
BLOCK DIAGRAMS

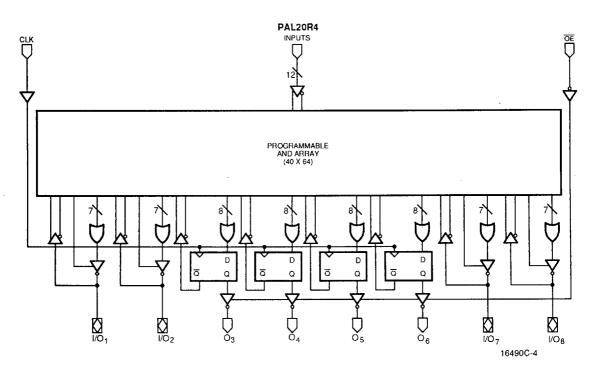




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BLOCK DIAGRAMS

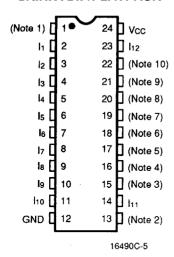




CONNECTION DIAGRAMS

Top View

SKINNYDIP/FLATPACK



Note: Pin 1 is marked for orientation.

Note	20L8	20R8	20R6	20R4
1	lo	CLK	CLK	CLK
2	l ₁₃	ŌĒ	le le	ŌĒ
3	O ₁	O ₁	I/O ₁	I/O ₁
4	I/O ₂	O ₂	O ₂	I/O ₂
5	I/O ₃	Оз	Оз	Оз
6	I/O ₄	O ₄	O ₄	O ₄
7	1/05	O ₅	O ₅	O ₅
8	1/06	O ₆	O ₆	O ₆
9	1/07	O ₇	O ₇	I/O ₇
10	O ₈	O ₈	I/O ₈	I/O8

PIN DESIGNATIONS

CLK = Clock
GND = Ground
I = Input
I/O = Input/Output
NC = No Connect

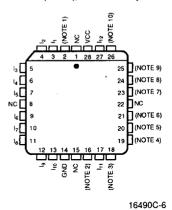
NC = No Connect O = Output

OE = Output Enable Vcc = Supply Voltage

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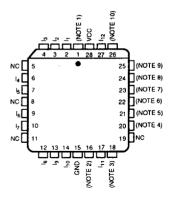
PLCC/LCC

JEDEC: Applies to -5, -7(-12/10 mil), -10(-15 mil), B-2 Series Only



PLCC

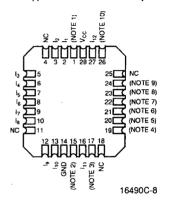
Applies to B and A Series Only



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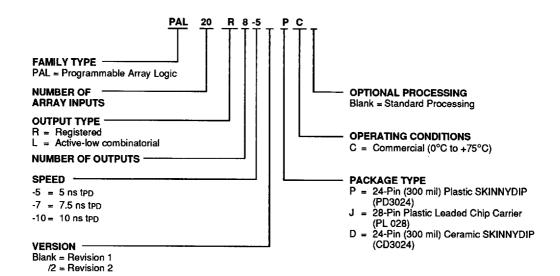
LCC

Applies to B and A Series Only



Commercial Products

AMD programmable logic products for commercial applications are available with several ordering options. The order number (Valid Combination) is formed by a combination of:



Valid Com	Valid Combinations					
PAL20L8-5						
PAL20R8-5						
PAL20R6-5						
PAL20R4-5	DO 10					
PAL20L8-10/2	PC, JC					
PAL20R8-10/2						
PAL20R6-10/2						
PAL20R4-10/2	L					
PAL20L8-7						
PAL20R8-7	DO 10 DO					
PAL20R6-7	PC, JC, DC					
PAL20R4-7						

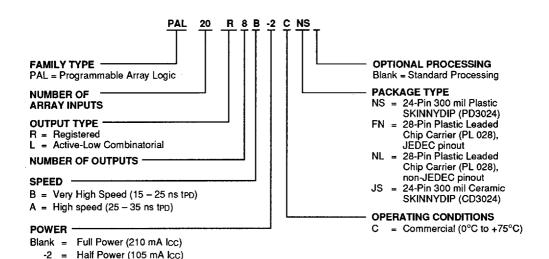
Valid Combinations

Valid Combinations lists configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations and to check on newly released combinations.



Commercial Products (MMI Marking Only)

AMD programmable logic products for commercial applications are available with several ordering options. The order number (Valid Combination) is formed by a combination of:



Valid Combinations						
PAL20L8 B-2 CNS, CFN, CJS						
PAL20R8						
PAL20R6	B, A	CNS, CNL, CJS				
PAL20R4						

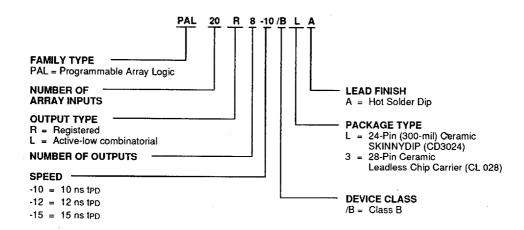
Valid Combinations

Valid Combinations lists configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations and to check on newly released combinations.

Note: Marked with MMI logo.

APL Products

AMD programmable logic products for Aerospace and Defense applications are available with several ordering options. APL (Approved Products List) products are fully compliant with MIL-STD-883 requirements. The order number (Valid Combination) is formed by a combination of:



Valid Combinations						
PAL20L8						
PAL20R8		(D) A (D) A				
PAL20R6	-10, -12, -15	/BLA, /B3A				
PAL20R4]					

Valid Combinations

Valid Combinations lists configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations and to check on newly released combinations.

Group A Tests

Group A Tests consist of Subgroups: 1, 2, 3, 7, 8, 9, 10, 11.

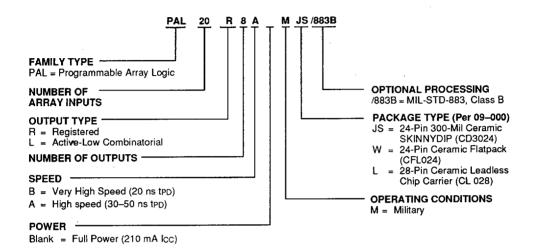
Military Burn-In

Military burn-in is in accordance with the current revision of MIL-STD-883, Test Methods 1015, Conditions A through E. Test conditions are selected at AMD's option.



APL Products (MMI Marking Only)

AMD programmable logic products for Aerospace and Defense applications are available with several ordering options. APL (Approved Products List) products are fully compliant with MIL-STD-883 requirements. The order number (Valid Combination) is formed by a combination of:



Valid Combinations							
PAL20L8							
PAL20R8	В 4	MJS/883B, MW/883B,					
PAL20R6	B, A	ML/883B					
PAL20R4							

Valid Combinations

Valid Combinations lists configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations and to check on newly released combinations.

Note: Marked with MMI logo.

Group A Tests

Group A Tests consist of Subgroups: 1, 2, 3, 7, 8, 9, 10, 11.

Military Burn-In

Military burn-in is in accordance with the current revision of MIL-STD-883, Test Methods 1015, Conditions A through E. Test conditions are selected at AMD's option.

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FUNCTIONAL DESCRIPTION Standard 24-Pin PAL Family

The standard 24-pin PAL family is comprised of four different devices, including both registered and combinatorial devices. All parts are produced with a fuse link at each input to the AND gate array, and connections may be selectively removed by applying appropriate voltages to the circuit. Using any of a number of development packages, these products can be rapidly programmed to any customized pattern. Extra test words are pre-programmed during manufacturing to ensure extremely high field programming yields, and provide extra test paths to achieve excellent parametric correlation.

Variable input/Output Pin Ratio

The registered devices have twelve dedicated input lines, and each combinatorial output is an I/O pin. The PAL20L8 has fourteen dedicated input lines, and only six of the eight combinatorial outputs are I/O pins. Buffers for device inputs have complementary outputs to provide user-programmable input signal polarity. Unused input pins should be tied to Voc or GND.

Programmable Three-State Outputs

Each output has a three-state output buffer with threestate control. On combinatorial outputs, a product term controls the buffer, allowing enable and disable to be a function of any product of device inputs or output feedback. The combinatorial output provides a bidirectional I/O pin, and may be configured as a dedicated input if the buffer is always disabled. On registered outputs, an input pin controls the enabling of the three-state outputs.

Registers with Feedback

Registered outputs are provided for data storage and synchronization. Registers are composed of D-type flip-flops that are loaded on the LOW-to-HIGH transition of the clock input.

Power-Up Reset

All flip-flops power-up to a logic LOW for predictable system initialization. Outputs of the PAL20R8 Family will be HIGH due to the active-low outputs. The Vcc rise must be monotonic and the reset delay time is 1000 ns maximum.

Register Preload

The register on the AMD marked 20R8, 20R6, and 20R4 devices can be preloaded from the output pins to facilitate functional testing of complex state machine designs. This feature allows direct loading of arbitrary states, making it unnecessary to cycle through long test vector sequences to reach a desired state. In addition, transitions from illegal states can be verified by loading illegal states and observing proper recovery.

Security Fuse

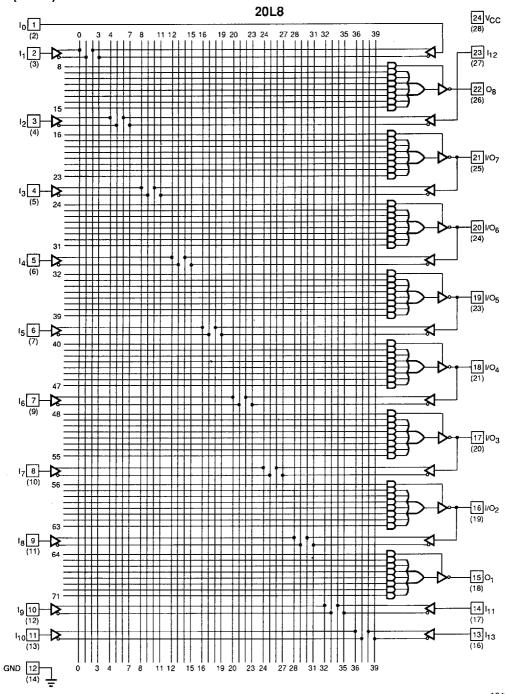
After programming and verification, a PAL20R8 Family design can be secured by programming the security fuse. Once programmed, this fuse defeats readback of the internal programmed pattern by a device programmer, securing proprietary designs from competitors. When the security fuse is programmed, the array will read as if every fuse is intact.

Quality and Testability

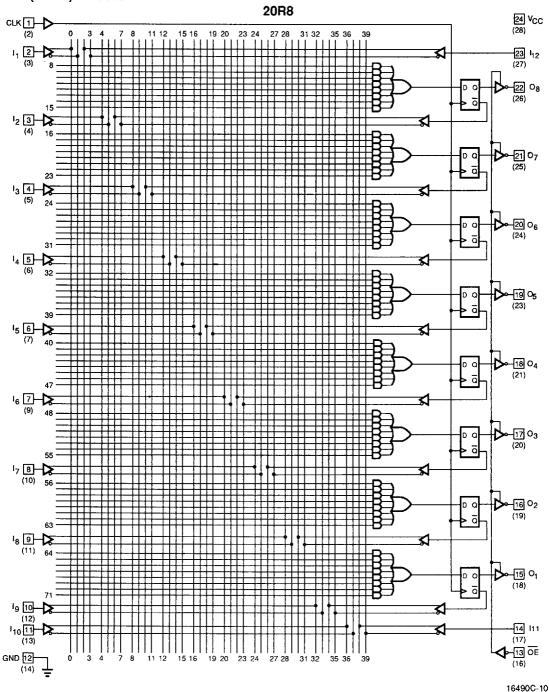
The PAL20R8 Family offers a very high level of built-in quality. Extra programmable fuses provide a means of verifying performance of all AC and DC parameters. In addition, this verifies complete programmability and functionality of the device to provide the highest programming yields and post-programming functional vields in the industry.

Technology

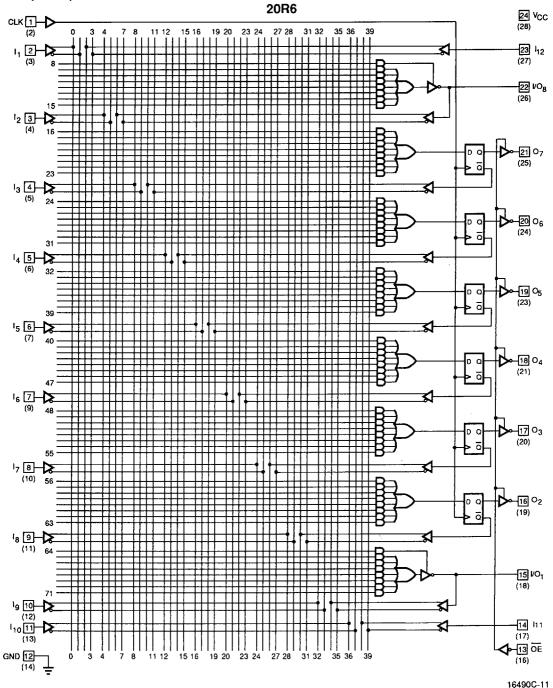
The PAL20R8-5, -7 and 10/2 are fabricated with AMD's oxide isolated process. The array connections are formed with highly reliable PtSi fuses. The PAL20R8B, B-2, and A series are fabricated with AMD's trench-isolated bipolar process. The array connections are formed with proven TiW fuses. These processes reduce parasitic capacitances and minimum geometries to provide higher performance.

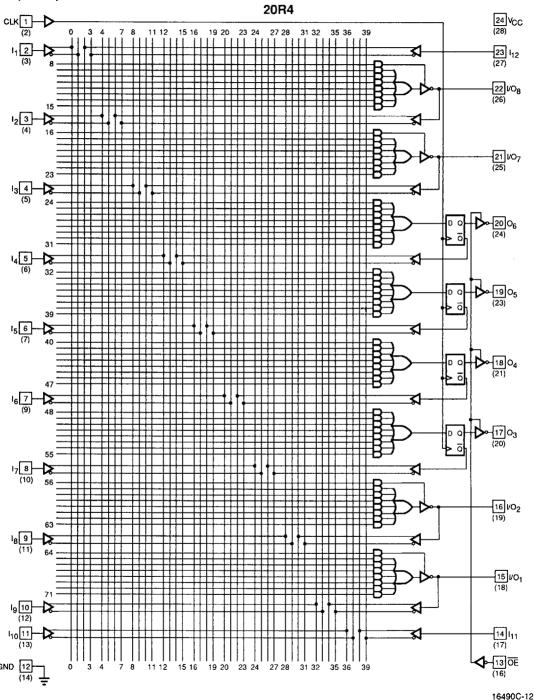


16490C-9











Storage Temperature65°C to +150°C
Ambient Temperature with Power Applied
Supply Voltage with Respect to Ground0.5 V to +7.0 V
DC Input Voltage1.2 V to V _{CC} + 0.5 V
DC Output or I/O Pin Voltage0.5 V to V _{CC} + 0.5 V
Static Discharge Voltage 2001 V

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ.

OPERATING RANGES

Commercial (C) Devices

Operating ranges define those limits between which the functionality of the device is guaranteed.

DC CHARACTERISTICS over COMMERCIAL operating ranges unless otherwise specified

Parameter Symbol	Parameter Description	Test Conditions	Min	Max	Unit
Vон	Output HIGH Voltage	IOH = -3.2 mA VIN = VIH or VIL VCC = Min	2.4		٧
Vol	Output LOW Voltage	IOL = 24 mA VIN = VIH or VIL VCC = Min		0.5	٧
ViH	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 1)	2.0		٧
VIL	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 1)		0.8	٧
Vı	Input Clamp Voltage	l _{IN} = −18 mA, Vcc = Min		-1.2	٧
lт	Input HIGH Current	Vin = 2.7 V, Vcc = Max (Note 2)		25	μА
lı.	Input LOW Current	Vin = 0.4 V, Vcc = Max (Note 2)		-250	μА
ŧı	Maximum Input Current	Vin = 5.5 V, Vcc = Max		1	mA
lozh	Off-State Output Leakage Current HIGH	Vout = 2.7 V, Vcc = Max Vin = ViH or ViL (Note 2)		100	μА
lozi	Off-State Output Leakage Current LOW	Vout = 0.4 V, Vcc = Max VIN = VIH or VIL (Note 2)		-100	μА
Isc	Output Short-Circuit Current	Vout = 0.5 V, Vcc = Max (Note 3)	-30	-130	mA
lcc	Supply Current	V _{IN} = 0 V, Outputs Open (I _{OUT} = 0 mA) Vcc = Max		210	mA

- 1. These are absolute values with respect to device ground and all overshoots due to system and/or tester noise are included.
- 2. I/O pin leakage is the worst case of IIL and IOZL (or IIH and IOZH).
- Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second.
 VOUT = 0.5 V has been chosen to avoid test problems caused by tester ground degradation.

CAPACITANCE (Note 1)

Parameter Symbol	Parameter Descriptio	n	Test Conditions	3	Тур	Unit
Cin	Input Capacitance	CLK, OE	VIN = 2.0 V	Vcc = 5.0 V	8	
		l1 - l12		TA = +25°C	5	ρF
Cour	Output Capacitance		Vout = 2.0 V	f = 1 MHz	8	

Note:

SWITCHING CHARACTERISTICS over COMMERCIAL operating ranges (Note 2)

Parameter Symbol	Parameter Des	Parameter Description					Unit
tpp	Input or Feedba	ck to Combinatorial Outpu	t	20L8, 20R6, 20R4	1	5	ns
ts	Setup Time from	n Input or Feedback to Clo	ck		4.5		ns
tн	Hold Time				0		ns
tco	Clock to Output			1	4	ns	
tskewr	Skew Between	Registered Outputs (Note			1	ns	
tw∟	Clock Width	LOW		20R8, 20R6,	4	-	ns
twн		HIGH	HIGH		4		ns
	Maximum	External Feedback	1/(ts + tco)		117		MHz
fmax	Frequency	Frequency Internal Feedback (fcnt)	ENT)		125		MHz
	(Note 5)	No Feedback	1/(twH + twL)	1	125		MHz
tpzx	OE to Output Er	ıable			1	6.5	ns
tpxz	OE to Output Disable				1	5	ns
tea	Input to Output Enable Using Product Term Control			20L8, 20R6,	2	6.5	ns
ten	Input to Output	Disable Using Product Ter	m Control	20R4	2	5	ns

- 2. See Switching Test Circuit for test conditions.
- 3. Output delay minimums for tPD, tCQ, tPZX tEA and tER are defined under best case conditions. Future process improvements may alter these values; therefore, minimum values are recommended for simulation purposes only.
- 4. Skew testing takes into account pattern and switching direction differences between outputs that have equal loading.
- These parameters are not 100% tested, but are calculated at initial characterization and at any time the design is modified where the frequency may be affected.

These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.



Storage Temperature65°C to +150°C
Ambient Temperature with Power Applied
Supply Voltage with Respect to Ground $\dots -0.5 \text{ V}$ to +7.0 V
DC Input Voltage $-1.2~V$ to Vcc + $0.5~V$
DC Output or I/O Pin Voltage

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ.

Static Discharge Voltage 2001 V

OPERATING RANGES

Commercial (C) Devices

Ambient Temperature (T_A)
Operating in Free Air 0°C to +75°C

Complet Matters (M.)

Supply Voltage (Vcc)

With Respect to Ground +4.75 V to +5.25 V

Operating ranges define those limits between which the functionality of the device is guaranteed.

DC CHARACTERISTICS over COMMERCIAL operating ranges unless otherwise specified

Parameter Symbol	Parameter Description	Test Conditions	Min	Max	Unit
Vон	Output HIGH Voltage	IOH = -3.2 mA VIN = VIH or VIL VCC = Min	2.4		٧
Vol	Output LOW Voltage	IOL = 24 mA VIN = VIH or VIL VCC = Min		0.5	٧
ViH	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 1)	2.0		. V
ViL	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 1)		0.8	٧
Vı	Input Clamp Voltage	lin = -18 mA, Vcc = Min		-1.2	٧
liH	Input HIGH Current	Vin = 2.7 V, Vcc = Max (Note 2)		25	μА
lıL	Input LOW Current	VIN = 0.4 V, Vcc = Max (Note 2)		-250	μА
=	Maximum Input Current	VIN = 5.5 V, Vcc = Max		1	mA
lozн	Off-State Output Leakage Current HIGH	Vout = 2.7 V, Vcc = Max Vin = ViH or ViL (Note 2)		100	μА
lozu	Off-State Output Leakage Current LOW	Vout = 0.4 V, Vcc = Max Vin = ViH or ViL (Note 2)		-100	μА
Isc	Output Short-Circuit Current	Vout = 0.5 V, Vcc = Max (Note 3)	-30	-130	mA
lcc	Supply Current	V _{IN} = 0 V, Outputs Open (lout = 0 mA) Vcc = Max		210	mA

- 1. These are absolute values with respect to device ground and all overshoots due to system and/or tester noise are included.
- 2. I/O pin leakage is the worst case of IIL and IOZL (or IIH and IOZH).
- Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second. Vout = 0.5 V
 has been chosen to avoid test problems caused by tester ground degradation.

CAPACITANCE (Note 1)

Parameter Symbol	Parameter Description	Test Conditions		Тур	Unit
Cin	Input Capacitance	Vin = 2.0 V	V _{CC} = 5.0 V	7	
Соит	Output Capacitance	Vout = 2.0 V	T _A = +25°C f = 1 MHz	8	ρF

Note:

SWITCHING CHARACTERISTICS over COMMERCIAL operating ranges (Note 2)

Parameter Symbol	Parameter Des	Parameter Description					Max	Unit
tPD	Input or Feedba	ck to			20L8, 20R6,	3	7.5	ns
	Combinatorial O	Output 1	Output S	witching	20R4	3	7	
ts	Setup Time from	n Input or Feedba	ack to Clo	ck		7		ns
tH	Hold Time					0		ns
tco	Clock to Output					1	6.5	ns
tskew	Skew Between	Registered Outpu	Registered Outputs (Note 4)				1	กร
twL	Clock Width	LOW	LOW		20R4	5		ns
twн		HIGH				5		ns
	Maximum	External Fee	edback	1/(ts + tco)		74		MHz
fmax	Frequency	Internal Fee	dback (fc	NT)		100		MHz
	(Note 5)	No Feedbac	:k	1/(twH + twL)		100		MHz
tpzx	OE to Output Er	OE to Output Enable			1	8	ns	
tpxz	OE to Output Di	Disable			1	8	ns	
tea	Input to Output I	t Enable Using Product Term Control		20L8, 20R6,	3	10	ns	
tER	Input to Output I	Disable Using Pro	oduct Ter	n Control	20R4	3	10	ns

- 2. See Switching Test Circuit for test conditions.
- Output delay minimums for tPD, tCD, tPZX tPXZ tEA and tER are defined under best case conditions. Future process improvements may alter these values; therefore, minimum values are recommended for simulation purposes only.
- 4. Skew is measured with all outputs switching in the same direction.
- 5. These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where the frequency may be affected.

These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.



Storage Temperature ... -65°C to +150°C

Ambient Temperature with
Power Applied ... -55°C to +125°C

Supply Voltage with
Respect to Ground ... -0.5 V to +7.0 V

DC Input Voltage ... -0.5 V to Vcc + 0.5 V

DC Output or I/O Pin Voltage ... -0.5 V to Vcc Max

DC Input Current ... -30 mA to 5 mA

Static Discharge Voltage ... 2001 V

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OPERATING RANGES

Commercial (C) Devices

Operating ranges define those limits between which the functionality of the device is guaranteed.

DC CHARACTERISTICS over COMMERCIAL operating ranges unless otherwise specified

Parameter Symbol	Parameter Description	Test Conditions	Min	Max	Unit
Vон	Output HIGH Voltage	IOH = -3.2 mA VIN = VIH or VIL VCC = Min	2.4		٧
Vol	Output LOW Voltage	IOL = 24 mA VIN = VIH or VIL VCC = Min		0.5	٧
VIH	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 1)	2.0		٧
ViL	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 1)		0.8	٧
Vi	Input Clamp Voltage	IIN = -18 mA, Vcc = Min		-1.5	٧
liH	Input HIGH Current	VIN = 2.4 V, VCC = Max (Note 2)		25	μΑ
l _{IL}	Input LOW Current	V _{IN} = 0.4 V, V _{CC} = Max (Note 2)		-250	μΑ
11	Maximum Input Current	VIN = 5.5 V, VCC = Max		100	μA
Іохн	Off-State Output Leakage Current HIGH	Vout = 2.4 V, Vcc = Max VIN = VIH or VIL (Note 2)		100	μА
lozL	Off-State Output Leakage Current LOW	Vout = 0.4 V, Vcc = Max Vin = ViH or ViL (Note 2)		-100	μА
Isc	Output Short-Circuit Current	Vout = 0.5 V, Vcc = Max (Note 3)	-30	-130	mA
lcc	Supply Current	VIN = 0 V, Outputs Open (Iout = 0 mA) Vcc = Max		210	mA

- 1. These are absolute values with respect to device ground and all overshoots due to system and/or tester noise are included.
- 2. I/O pin leakage is the worst case of IIL and IOZL (or IIH and IOZH).
- Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second. Vout = 0.5 V
 has been chosen to avoid test problems caused by tester ground degradation.

CAPACITANCE (Note 1)

Parameter Symbol	Parameter Description	Test Conditions		Тур	Unit
Cin	Input Capacitance	VIN = 2.0 V	V _{CC} = 5.0 V	7	
Соит	Output Capacitance	Vout = 2.0 V	T _A = 25°C f = 1 MHz	8	pF

Note:

SWITCHING CHARACTERISTICS over COMMERCIAL operating ranges (Note 2)

Parameter Symbol	Parameter Des	Parameter Description				Max	Unit
tpp	Input or Feedba	ck to Combinatorial Outp	out	20L8, 20R6,			
40				20R4	3	10	กร
ts	Setup Time from	Input or Feedback to C	lock		10		ns
tн	Hold Time				0		ns
tco	Clock to Output				3	8	ns
twL	Clock Width	LOW		20R8, 20R6,	7		ns
twн	CIOCK WIGHT	HIGH	HIGH		7		ns
	Maximum	External Feedback	1/(ts + tco)	7	55.5		MHz
fMAX	Frequency	Internal Feedback (fo	ONT)	1	58.8		MHz
	(Note 4)	No Feedback	1/(twH + twL)	7	71.4		MHz
tpzx	OE to Output Er	ıable		7	2	10	ns
tpxz	OE to Output Di	able]	2	10	ns
tea .	Input to Output I	ut Enable Using Product Term Control		20L8, 20R6,	3	10	ns
tER	Input to Output I	Disable Using Product To	erm Control	20R4	3	10	ns

- 2. See Switching Test Circuit for test conditions.
- Output delay minimums for tPD tCQ tPZX tPXZ tEA and tER are defined under best case conditions. Future process improvements
 may alter these values; therefore, minimum values are recommended for simulation purposes only.
- 4. These parameters are not 100% tested, but are calculated at initial characterization and at any time the design is modified where the frequency may be affected.

These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.



Storage Temperature -65°C to +150°C

Ambient Temperature with
Power Applied -55°C to +125°C

Supply Voltage with
Respect to Ground -0.5 V to +7.0 V

DC Input Voltage -1.5 V to Vcc + 0.5 V

DC Output or I/O

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ.

Pin Voltage −0.5 V to V_{CC} + 0.5 V

OPERATING RANGES

Commercial (C) Devices

Ambient Temperature (T_A)

Operating in Free Air 0°C to +75°C

Supply Voltage (Vcc)

with Respect to Ground +4.75 V to +5.25 V

Operating ranges define those limits between which the functionality of the device is guaranteed.

DC CHARACTERISTICS over COMMERCIAL operating ranges unless otherwise specified

Parameter Symbol	Parameter Description	Test Conditions	Min	Max	Unit
Vон	Output HIGH Voltage	IOH = -3.2 mA VIN = VIH or VIL VCC = Min	2.4		٧
Vol	Output LOW Voltage	IOL = 24 mA VIN = VIH or VIL VCC = Min		0.5	٧
ViH	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 1)	2.0		٧
VIL	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 1)		0.8	٧
Vı	Input Clamp Voltage	IIN = -18 mA, Vcc = Min		-1.5	٧
lн	Input HIGH Current	Vin = 2.7 V, Vcc = Max (Note 2)		25	μΑ
lı.	Input LOW Current	VIN = 0.4 V, Vcc = Max (Note 2)		-250	μΑ
ħ	Maximum Input Current	V _{IN} = 5.5 V, V _{CC} = Max	7	100	μΑ
lozн	Off-State Output Leakage Current HIGH	Vout = 2.7 V, Vcc = Max VIN = VIH or VIL (Note 2)		100	μА
lozL	Off-State Output Leakage Current LOW	Vout = 0.4 V, Vcc = Max VIN = VIH or VIL (Note 2)		-100	μА
Isc	Output Short-Circuit Current	Vout = 0.5 V, Vcc = Max (Note 3)	-30	-130	mA
lcc	Supply Current	VIN = 0 V, Outputs Open (Iout = 0 mA) Vcc = Max		210	mA

- 1. These are absolute values with respect to device ground and all overshoots due to system and/or tester noise are included.
- 2. I/O pin leakage is the worst case of IIL and IOZL (or IIH and IOZH).
- 3. Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second. Vout = 0.5 V has been chosen to avoid test problems caused by tester ground degradation.



SWITCHING CHARACTERISTICS over COMMERCIAL operating ranges (Note 1)

			1 3 (************************				
Parameter Symbol	Parameter Des	cription		,	Min	Max	Unit
tPD	Input or Feedba	ck to Combinatorial Outpu	k to Combinatorial Output			15	ns
ts	Setup Time from	n Input or Feedback to Clo	ock		15		ns
tH	Hold Time				0		ns
tco	Clock to Output	or Feedback		20R8, 20R6,		12	ns
twL	Clock Width	LOW		20R4	10		ns
twn		HIGH		ĺ	12		ns
6	Maximum	External Feedback	1/(ts + tco)		37		MHz
fmax	(Note 2) No Feedback	No Feedback	1/(twH + twL)		45		MHz
tpzx	OE to Output Er	nable				15	ns
tpxz	OE to Output Di	to Output Disable				12	ns
tea	Input to Output I	put to Output Enable Using Product Term Control		20L8, 20R6,		18	ns
tea	Input to Output I	Disable Using Product Ter	m Control	20R4		15	ns

^{1.} See Switching Test Circuit for test conditions.

^{2.} These parameters are not 100% tested, but are calculated at initial characterization and at any time the design is modified where frequency may be affected.



Storage Temperature	65°C to +150°C
Ambient Temperature with Power Applied	–55°C to +125°C
Supply Voltage with Respect to Ground	0.5 V to +7.0 V
DC Input Voltage	$$ –1.5 V to Vcc + 0.5 V
DC Output or I/O	-0.5 V to Vcc + 0.5 V

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ.

OPERATING RANGES

Commercial (C) Devices

Operating ranges define those limits between which the functionality of the device is guaranteed.

DC CHARACTERISTICS over COMMERCIAL operating ranges unless otherwise specified

Parameter Symbol	Parameter Description	Test Conditions	Min	Max	Unit
Vон	Output HIGH Voltage	IOH = -3.2 mA VIN = VIH or VIL VCC = Min	2.4		٧
Vol	Output LOW Voltage	IOL = 24 mA VIN = VIH or VIL VCC = Min		0.5	٧
ViH	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 1)	2.0		٧
VIL	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 1)		0.8	٧
Vı	Input Clamp Voltage	lin = −18 mA, Vcc = Min		-1.5	٧
lıн	Input HIGH Current	V _{IN} = 2.7 V, V _{CC} = Max (Note 2)		25	μА
lı.	Input LOW Current	Vin = 0.4 V, Vcc = Max (Note 2)		-250	μА
l _l	Maximum Input Current	V _{IN} = 5.5 V, V _{CC} = Max		100	μΑ
lozн	Off-State Output Leakage Current HIGH	Vout = 2.7 V, Vcc = Max Vin = ViH or ViL (Note 2)		100	μА
lozl	Off-State Output Leakage Current LOW	Vout = 0.4 V, Vcc = Max VIN = VIH or VIL (Note 2)		-100	μΑ
Isc	Output Short-Circuit Current	Vout = 0.5 V, Vcc = Max (Note 3)	-30	-130	mA
lcc	Supply Current	VIN = 0 V, Outputs Open (Iout = 0 mA) Vcc = Max		105	mA

- 1. These are absolute values with respect to device ground and all overshoots due to system and/or tester noise are included.
- 2. I/O pin leakage is the worst case of IIL and IOZL (or IIH and IOZH).
- 3. Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second.

 VOUT = 0.5 V has been chosen to avoid test problems caused by tester ground degradation.



SWITCHING CHARACTERISTICS over COMMERCIAL operating ranges (Note 1)

Parameter Symbol	Parameter Des	cription			Min	Max	Unit
tPD	Input or Feedba	ck to Combinatorial Outpu	k to Combinatorial Output			25	ns
ts	Setup Time from	n Input or Feedback to Clo	ck		25		ns
tH	Hold Time				0		ns
tco	Clock to Output					15	ns
twL	Clock Width	LOW		20R4	15		ns
twn		HIGH			15		ns
	Maximum	External Feedback	1/(ts + tco)		25		MHz
fMAX	Frequency	Internal Feedback (fo	NT)		28.5		MHz
	(Note 3)	No Feedback	1/(tw+ + twL)	1	33.3		MHz
tpzx	OE to Output En	nable]		20	ns
t PXZ	OE to Output Dis	out Disable				20	ns
İ EA	Input to Output E	t Enable Using Product Term Control		20L8, 20R6,		25	ns
ter	Input to Output [Disable Using Product Ter	m Control	20R4		25	ns

- 1. See Switching Test Circuit for test conditions.
- 2. Calculated from measured fMAX internal.
- These parameters are not 100% tested, but are calculated at initial characterization and at any time the design is modified where frequency may be affected.



Storage Temperature	65°C to +150°C
Ambient Temperature with Power Applied	–55°C to +125°C
Supply Voltage with Respect to Ground	0.5 V to +7.0 V
DC Input Voltage	-1.5 V to Vcc + 0.5 V
DC Output or I/O	0.5.V.to.Voo.

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ.

OPERATING RANGES

Commercial (C) Devices

Operating in Free Air 0°C to +7	′5°C
Supply Voltage (Vcc) with Respect to Ground +4.75 V to +5.3	25 V

Operating ranges define those limits between which the functionality of the device is guaranteed.

DC CHARACTERISTICS over COMMERCIAL operating ranges unless otherwise specified

Parameter Symbol	Parameter Description	Test Conditions	Min	Max	Unit
Vон	Output HIGH Voltage	IOH = -3.2 mA VIN = VIH or VIL VCC = Min	2.4		٧
Vol	Output LOW Voltage	IOL = 24 mA VIN = VIH or VIL VCC = Min		0.5	٧
ViH	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 1)	2.0		٧
ViL	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 1)		0.8	٧
Vı	Input Clamp Voltage	lin = −18 mA, Vcc = Min		-1.5	٧
IIH	Input HIGH Current	VIN = 2.7 V, Vcc = Max (Note 2)		25	μΑ
lıL	Input LOW Current	V _{IN} = 0.4 V, V _{CC} = Max (Note 2)		-250	μΑ
lı .	Maximum Input Current	Vin = 5.5 V, Vcc = Max		100	μА
Іохн	Off-State Output Leakage Current HIGH	Vout = 2.7 V, Vcc = Max VIN = VIH or VIL (Note 2)		100	μА
lozl	Off-State Output Leakage Current LOW	Vout = 0.4 V, Vcc = Max VIN = VIH or VIL (Note 2)		-100	μА
Isc	Output Short-Circuit Current	Vout = 0.5 V, Vcc = Max (Note 3)	-30	-130	mA
lcc	Supply Current	VIN = 0 V, Outputs Open (IOUT = 0 mA) VCC = Max		210	mA

- 1. These are absolute values with respect to device ground and all overshoots due to system and/or tester noise are included.
- 2. I/O pin leakage is the worst case of IIL and IOZL (or IIH and IOZH).
- Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second. Vour = 0.5 V
 has been chosen to avoid test problems caused by tester ground degradation.



SWITCHING CHARACTERISTICS over COMMERCIAL operating ranges (Note 1)

Parameter Symbol	Parameter Des	Parameter Description					Unit
tPD	Input or Feedba	ck to Combinatorial Outpu	20L8, 20R6, 20R4		25	ns	
ts	Setup Time fron	n Input or Feedback to Clo	ock		25		ns
tH	Hold Time]	0		ns
tco	Clock to Output			20R8, 20R6,		15	ns
twL	Clock Width	LOW		20R4	15		ns
twn		HIGH			15		ns
	Maximum	External Feedback	1/(ts + tco)		25		MHz
fmax	Frequency (Note 3)	Internal Feedback (fo	NT)		28.5		MHz
	(.16.6 6)	No Feedback	1/(twH + twL)		33		MHz
tPZX	OE to Output Er	nable				20	ns
tPXZ	OE to Output Di	sable				20	ns
tea .	Input to Output i	Enable Using Product Term Control 20L8, 2		20L8, 20R6,		25	ns
tER	Input to Output I	Disable Using Product Ter	m Control	20R4		25	ns

- 1. See Switching Test Circuit for test conditions.
- 2. Calculated from measured fMAX internal.
- These parameters are not 100% tested, but are calculated at initial characterization and at any time the design is modified where frequency may be affected.



- ·
Storage Temperature $\ \dots \ -65^{\circ}\text{C}$ to $+150^{\circ}\text{C}$
Ambient Temperature With Power Applied55°C to +125°C
Supply Voltage with Respect to Ground $\dots -0.5 \text{ V to } +7.0 \text{ V}$
DC Input Voltage $-1.2~V~$ to Vcc + 0.5 V
DC Output or I/O Pin Voltage
Static Discharge Voltage 2001 V

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ. Absolute Maximum Ratings are for system design reference; parameters given are not tested.

OPERATING RANGES

Military (M) Devices (Note 1)

Operating Case (Tc)

Temperature -55°C to +125°C

Supply Voltage (Vcc)

with Respect to Ground +4.50 V to +5.50 V

Operating ranges define those limits between which the functionality of the device is guaranteed.

Note:

 Military products are 100% tested at T_C = +25°C, +125°C, and -55°C.

DC CHARACTERISTICS over MILITARY operating ranges unless otherwise specified (Note 2)

Parameter Symbol	Parameter Description	Test Conditions	Min	Max	Unit
Vон	Output HIGH Voltage	IOH = -2 mA VIN = VIH or VIL VCC = Min	2.4		٧
Vol	Output LOW Voltage	I _{OL} = 12 mA		0.5	٧
VIH	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 3)	2.0		>
VIL	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 3)		0.8	٧
Vı	Input Clamp Voltage	I _{IN} = -18 mA, V _{CC} = Min		-1.2	V
lн	Input HIGH Current	V _{IN} = 2.4 V, V _{CC} = Max (Note 4)		25	μА
l _{IL}	Input LOW Current	VIN = 0.4 V, Vcc = Max (Note 4)		-250	μА
lı .	Maximum Input Current	VIN = 5.5 V, VCC = Max		1	mA
ЮZН	Off-State Output Leakage Current HIGH	Vout = 2.4 V, Vcc = Max V _{IN} = V _{IH} or V _{IL} (Note 4)		100	μΑ
lozu	Off-State Output Leakage Current LOW	Vout = 0.4 V, Vcc = Max V _{IN} = V _{IH} or V _{IL} (Note 4)		-100	μА
Isc	Output Short-Circuit Current	Vout = 0.5 V, Vcc = Max (Note 5)	-30	-130	mA
lcc	Supply Current	V _{IN} = 0 V, Outputs Open (Iout = 0 mA) V _{CC} = Max		210	mA

- 2. For APL Products, Group A, Subgroups 1, 2, and 3 are tested per MIL-STD-883, Method 5005, unless otherwise noted.
- 3. V_{IL} and V_{IH} are input conditions of output tests and are not themselves directly tested. V_{IL} and V_{IH} are absolute voltages with respect to device ground and include all overshoots due to system and/or tester noise. Do not attempt to test these values without suitable equipment.
- 4. I/O pin leakage is the worst case of IIL and lozL (or IIH and lozH).
- 5. Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second. Vour = 0.5 V has been chosen to avoid test problems caused by tester ground degradation.



CAPACITANCE (Note 1)

Parameter Symbol	Parameter Descriptions	scriptions Test Conditions		Тур	Unit
Cin	Input Capacitance	VIN = 2.0 V	Vcc = 5.0 V	9	
Соит	Output Capacitance	Vout = 2.0 V	TA = +25°C f = 1 MHz	10	pF

Note:

SWITCHING CHARACTERISTICS over MILITARY operating ranges (Note 2)

						`	•		
	Parameter Description			-10		-12			
Parameter Symbol				Min (Note 3)	Max	Min (Note 3)	Max	Unit	
tPD	Input or Feedba	ack to Combinatorial Output		20L8, 20R6, 20R4	3	10	3	12	ns
ts	Setup Time from	Input or Feedback to Ck	ock		10		12		ns
tн	Hold Time			1	0	-	0		ns
tco	Clock to Output			1	3	10	3	12	ns
tskew	Skew Between F	Registered Outputs (Note 4)		1	-	1		1	ns
twL	Clock Width	LOW		20R8	8		10		ns
twH		HIGH		20R6, 20R4	8		10		ns
fmax	Maximum Frequency (Note 5)	External Feedback	1/(ts + tco)		50		41.7		MHz
		Internal Feedback	(fCNT)		62.5		50		MHz
		No Feedback	1/(tw+ + twL)		62.5		50		MHz
tPZX	OE to Output En	able (Note 5)		1 i	3	12	3	15	ns
tPXZ	OE to Output Dis	sable (Note 5)			3	12	3	15	ns
tea	Input to Output E Term Control (No	ut Enable Using Product (Note 5)		20L8,	3	12	3	15	ns
ter	Input to Output Disable Using Product Term Control (Note 5)		20R6, 20R4	3	12	3	15	ns	

- See Switching Test Circuit for test conditions. For APL products Group A, Subgroups 9, 10, and 11 are tested per MIL-STD-883, Method 5005, unless otherwise noted.
- Output delay minimums for tPD tCQ tPZX tEA and tER are defined under best case conditions. Future process improvements may alter these values; therefore, minimum values are recommended for simulation purposes only.
- 4. Skew is measured with all outputs switching in the same direction.
- These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where these parameters may be affected.

These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.



Storage Temperature	65°C to +150°C
Ambient Temperature with Power Applied	55°C to +125°C
Supply Voltage with Respect to Ground	0.5 V to +7.0 V
DC Input Voltage	0.5 V to +5.5 V
DC Output or I/O Pin Voltage	–0.5 V to Vcc Max
DC Input Current	30 mA to +5 mA

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ. Absolute Maximum Ratings are for system design reference; parameters given are not tested.

OPERATING RANGES

Military (M) Devices (Note 1)

minitary (m) before (note)	,
Ambient Temperature (T _A) Operating in Free Air	–55°C Min
Operating Case (Tc) Temperature	+125°C Max
Supply Voltage (Vcc) with	+4 50 V to +5 50 V

Operating ranges define those limits between which the functionality of the device is guaranteed.

Note:

 Military products are tested at Tc = +25°C, +125°C, and -55°C per MIL-STD-883.

DC CHARACTERISTICS over MILITARY operating ranges unless otherwise specified (Note 2)

Parameter Symbol	Parameter Description	Test Conditions	Min	Max	Unit
Vон	Output HIGH Voltage	IOH = -2 mA VIN = VIH or VIL VCC = Min	2.4		V
Vol	Output LOW Voltage	IOL = 12 mA VIN = VIH or VIL VCC = Min		0.5	٧
ViH	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 3)	2.0		٧
VIL	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 3)		0.8	٧
Vı	Input Clamp Voltage	I _{IN} = -18 mA, Vcc = Min		-1.5	٧
Іін	Input HIGH Current	VIN = 2.4 V, Vcc = Max (Note 4)		25	μΑ
lıL	Input LOW Current	VIN = 0.4 V, Vcc = Max (Note 4)		-250	μΑ
lı .	Maximum Input Current	VIN = 5.5 V, Vcc = Max		100	μΑ
Іогн	Off-State Output Leakage Current HIGH	Vout = 2.7 V, Vcc = Max Vin = ViH or ViL (Note 4)		100	μΑ
lozi	Off-State Output Leakage Current LOW	Vout = 0.4 V, Vcc = Max VIN = VIH or VIL (Note 4)		-100	μА
Isc	Output Short-Circuit Current	Vout = 0.5 V, Vcc = Max (Note 5)	-30	-130	mA
lcc	Supply Current	V _{IN} = 0 V, Outputs Open (I _{OUT} = 0 mA) V _{CC} = Max		210	mA

Notes:

- 2. For APL Products, Group A, Subgroups 1, 2, and 3 are tested per MIL-STD-883, Method 5005, unless otherwise noted.
- 3. V_{IL} and V_{IH} are input conditions of output tests and are not themselves directly tested. V_{IL} and V_{IH} are absolute voltages with respect to device ground and include all overshoots due to system and/or tester noise. Do not attempt to test these values without suitable equipment.
- 4. I/O pin leakage is the worst case of IIL and lozL (or IIH and lozH).
- 5. Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second. Vout = 0.5 V has been chosen to avoid test problems caused by tester ground degradation.

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CAPACITANCE (Note 1)

Parameter Symbol	Parameter Description	Test Conditions	3		Тур	Unit	
Cin	Input Capacitance	VIN = 2.0 V	V _{CC} = 5.0 V	CLK, OE	12		
			T _A = 25°C	Other Inputs	7	ρF	
Соит	Output Capacitance	Vout = 2.0 V	f = 1 MHz	Outputs	8		

Note:

SWITCHING CHARACTERISTICS over MILITARY operating ranges (Note 2)

Parameter Symbol	Parameter Description				Min (Note 3)	Max	Unit
tPD	Input or Feedba Combinatorial (20L8, 20R6, 20R4	3	15	ns	
ts	Setup Time from	m Input or Feedback to Cio	ck		15		ns
tн	Hold Time				0		ns
tco	Clock to Output			3	13	ns	
twL	Clock Width	LOW			10		ns
twн		HIGH		20L8, 20R6,	10		ns
	Maximum	External Feedback	1/(ts + tco)	20R4 .	35.7		MHz
fmax	Frequency	Internal Feedback (fc	NT)		37		MHz
	(Note 5)	No Feedback	1/(twH + twL)		50		MHz
tpzx	OE to Output E	nable (Note 6)			3	15	ns
texz	OE to Output D	isable (Note 6)			3	15	ns
tEA	Input to Output Term Control (N	Enable Using Product Note 6)			3	15	ns
ten	Input to Output Term Control (N	Disable Using Product Note 6)		20L8, 20R6, 20R4	3	15	ns

- See Switching Test Circuit for test conditions. For APL products Group A, Subgroups 9, 10, and 11 are tested per MIL-STD-883, Method 5005, unless otherwise noted.
- Output delay minimums for tpD, tcO, tpZX, tpXZ, teA, and ten are defined under best case conditions. Future process improvements may alter these values; therefore, minimum values are recommended for simulation purposes only.
- 4. Calculated from measured fMAX internal.
- These parameters are not 100% tested, but are calculated at initial characterization and at any time the design is modified where frequency may be affected.
- 6. These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where these parameters may be affected.

These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.



Storage Temperature65°C to +150°C
Ambient Temperature with Power Applied55°C to +125°C
Supply Voltage with Respect to Ground0.5 V to +7.0 V
DC Input Voltage1.5 V to +5.5 V
DC Output or I/O Pin Voltage

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ. Absolute Maximum Ratings are for system design reference; parameters given are not tested.

OPERATING RANGES

Military (M) Devices (Note 1)

, , , , , , , , , , , , , , , , , , ,	
Ambient Temperature (T _A) Operating in Free Air	–55°C Min
Operating Case (Tc) Temperature	⊧125°C Max
Supply Voltage (Vcc) with Respect to Ground +4.50 \	√ to +5.50 V

Note:

 Military products are tested at Tc = +25°C, +125°C, and -55°C per MIL-STD-883.

Operating ranges define those limits between which the functionality of the device is guaranteed.

DC CHARACTERISTICS over MILITARY operating ranges unless otherwise specified (Note 2)

Parameter Symbol	Parameter Description	Test Conditions	Min	Max	Unit
Vон	Output HIGH Voltage	IOH = -2 mA VIN = VIH or VIL VCC = Min	2.4		٧
Vol	Output LOW Voltage	I _{OL} = 12 mA V _{IN} = V _{IH} or V _{IL} V _{CC} = Min		0.5	V
ViH	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 3)	2.0		V
VIL	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 3)		8.0	٧
Vı	Input Clamp Voltage	I _{IN} = -18 mA, V _{CC} = Min		-1.5	٧
lıin	Input HIGH Current	V _{IN} = 2.4 V, V _{CC} = Max (Note 4)		25	μΑ
lıL	Input LOW Current	VIN = 0.4 V, VCC = Max (Note 4)		-250	μΑ
lı	Maximum Input Current	VIN = 5.5 V, VCC = Max		1	mA
ЮЗН	Off-State Output Leakage Current HIGH	Vout = 2.4 V, Vcc = Max Vin = ViH or ViL (Note 4)		100	μΑ
lozı	Off-State Output Leakage Current LOW	Vout = 0.4 V, Vcc = Max V _{IN} = V _{IH} or V _{IL} (Note 4)		-100	μА
Isc	Output Short-Circuit Current	Vout = 0.5 V, Vcc = Max (Note 5)	-30	-130	mA
lcc	Supply Current	V _{IN} = 0 V, Outputs Open (I _{OUT} = 0 mA) V _{CC} = Max		210	mA

- 2. For APL Products, Group A, Subgroups 1, 2, and 3 are tested per MIL-STD-883, Method 5005, unless otherwise noted.
- 3. VIL and VIH are input conditions of output tests and are not themselves directly tested. VIL and VIH are absolute voltages with respect to device ground and include all overshoots due to system and/or tester noise. Do not attempt to test these values without suitable equipment.
- 4. I/O pin leakage is the worst case of IIL and IOZL (or IIH and IOZH).
- Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second. Vouτ = 0.5 V
 has been chosen to avoid test problems caused by tester ground degradation.



SWITCHING CHARACTERISTICS over MILITARY operating ranges (Note 1)

Parameter Symbol	Parameter Des		Min	Max	Unit		
tPD	Input or Feedba	ck to Combinatorial Outpu	20L8, 20R6, 20R4		20	ns	
ts	Setup Time from	Input or Feedback to Clo	ock		20		ns
tH	Hold Time				0		ns
tco	Clock to Output	or Feedback				15	ns
twL	Clarate Middle	LOW			12		ns
twн	Clock Width	HIGH		20R8, 20R6,	12		ns
fmax	Maximum Frequency	External Feedback	1/(ts + tco)	20R4	28.5		MHz
	(Note 2)	No Feedback	1/(twH + twL)		41.6		MHz
tpzx	OE to Output Er	able (Note 3)				20	ns
tPXZ	OE to Output Di	OE to Output Disable (Note 3)				20	ns
tEA	Input to Output E Term Control (N	ut Enable Using Product (Note 3) 20L8, 20R6,				25	ns
ten	Input to Output [Term Control (N	Disable Using Product ote 3)	20R4		20	ns	

- See Switching Test Circuit for test conditions. For APL products Group A, Subgroups 9, 10, and 11 are tested per MIL-STD-883, Method 5005, unless otherwise noted.
- 2. These parameters are not 100% tested, but are calculated at initial characterization and at any time the design is modified where frequency may be affected.
- These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where these parameters may be affected.



Storage Temperature65°C	C to +150°C
Ambient Temperature with Power Applied55°C	C to +125°C
Supply Voltage with Respect to Ground0.5	V to +7.0 V
DC Input Voltage1.5	V to $+5.5$ V
DC Output or I/O Pin Voltage	5.5 V

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ. Absolute Maximum Ratings are for system design reference; parameters given are not tested.

OPERATING RANGES

Military (M) Devices (Note 1)

Ambient Temperature (T _A) Operating in Free Air	–55°C Min
Operating Case (Tc) Temperature +	125°C Max
Supply Voltage (Vcc) with Respect to Ground +4.50 V	to +5.50 V

Operating ranges define those limits between which the functionality of the device is guaranteed.

Note:

 Military products are tested at Tc = +25°C, +125°C, and -55°C per MIL-STD-883.

DC CHARACTERISTICS over MILITARY operating ranges unless otherwise specified (Note 2)

Parameter Symbol	Parameter Description	Test Conditions	Min	Max	Unit
Vон	Output HIGH Voltage	I _{OH} = -2 mA V _{IN} = V _{IH} or V _{IL} V _{CC} = Min	2.4		V
. Vol	Output LOW Voltage	IOL = 12 mA VIN = VIH or VIL VCC = Min		0.5	>
VIH	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 3)	2.0		٧
VIL	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 3)		0.8	٧
Vı	Input Clamp Voltage	I _{IN} = -18 mA, Vcc = Min		-1.5	>
lн	Input HIGH Current	VIN = 2.4 V, VCC = Max (Note 4)		25	μΑ
1 ₁ L	Input LOW Current	V _{IN} = 0.4 V, V _{CC} = Max (Note 4)		-250	μΑ
-	Maximum Input Current	VIN = 5.5 V, VCC = Max		1	mA
Іохн	Off-State Output Leakage Current HIGH	Vout = 2.4 V, Vcc = Max VIN = VIH or VIL (Note 4)		100	μΑ
lozi.	Off-State Output Leakage Current LOW	Vout = 0.4 V, Vcc = Max Vin = ViH or ViL (Note 4)		-100	μА
Isc	Output Short-Circuit Current	Vout = 0.5 V, Vcc = Max (Note 5)	-30	-130	mA
lcc	Supply Current	V _{IN} = 0 V, Outputs Open (lout = 0 mA) V _{CC} = Max		210	mA

Notes:

- 2. For APL Products, Group A, Subgroups 1, 2, and 3 are tested per MIL-STD-883, Method 5005, unless otherwise noted.
- 3. VIL and VIH are input conditions of output tests and are not themselves directly tested. VIL and VIH are absolute voltages with respect to device ground and include all overshoots due to system and/or tester noise. Do not attempt to test these values without suitable equipment.
- 4. I/O pin leakage is the worst case of IIL and IOZL (or IIH and IOZH).
- Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second. Vout = 0.5 V
 has been chosen to avoid test problems caused by tester ground degradation.

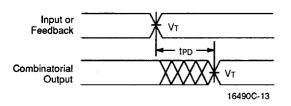
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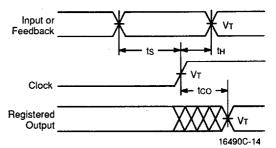
SWITCHING CHARACTERISTICS over MILITARY operating ranges (Note 1)

Parameter Symbol	Parameter Desc		Min	Max	Unit		
tPD	Input or Feedbac	ck to Combinatorial Output 20L8, 20R6, 20R4				30	ns
ts	Setup Time from	Input or Feedback to Clo	ck		30		ns
tн	Hold Time				0		ns
tco	Clock to Output	or Feedback	Feedback				ns
twl	Ole als Müsles	LOW			20		ns
twн	Clock Width	Clock Width .HIGH			20		ns
fMAX	Maximum	External Feedback	1/(ts + tco)	20R4 -	20		MHz
	Frequency (Note 2)	No Feedback	1/(twH + twL)		25		MHz
tpzx	OE to Output En	able (Note 3)				25	ns
tpxz	OE to Output Dis	sable (Note 3)				25	ns
t EA	Input to Output Enable Using Product Term Control (Note 3) 20L8, 20R6,					30	ns
ter	Input to Output I Term Control (N	Disable Using Product ote 3)	20R4		30	ns	

- See Switching Test Circuit for test conditions. For APL products Group A, Subgroups 9, 10, and 11 are tested per MIL-STD-883, Method 5005, unless otherwise noted.
- 2. These parameters are not 100% tested, but are calculated at initial characterization and at any time the design is modified where frequency may be affected.
- These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where these parameters may be affected.

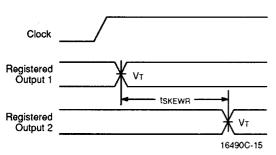
SWITCHING WAVEFORMS



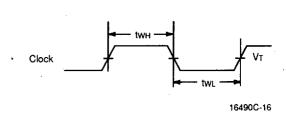


Combinatorial Output

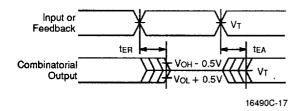
Registered Output



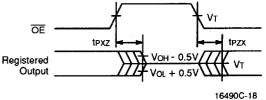
Registered Output Skew



Clock Width



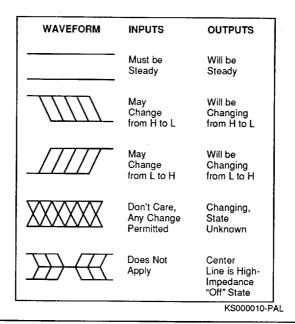
Input to Output Disable/Enable



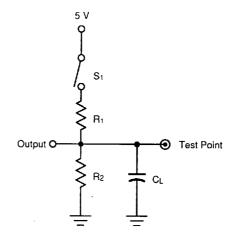
OE to Output Disable/Enable

- 1. $V_T = 1.5 V$
- 2. Input pulse amplitude 0 V to 3.0 V
- 3. Input rise and fall times 2 ns 3 ns typical

KEY TO SWITCHING WAVEFORMS



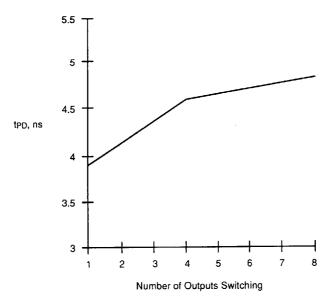
SWITCHING TEST CIRCUIT



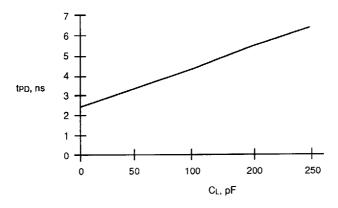
16490C-19

			Comr	nercial	Mitit	ary	Measured
Specification	S ₁	CL	R:	R₂	R ₁	R ₂	Output Value
tPD, tCO	Closed			For -5: 200 Ω			1.5 V
tPZX, tEA	Z → H: Open Z → L: Closed	50 pF	200 Ω	For rest 390 Ω	390 Ω	750 Ω	1.5 V
tpxz, ten	H → Z: Open L → Z: Closed	5 pF					H → Z: V _{OH} − 0.5 V L → Z: V _{OL} + 0.5 V

MEASURED SWITCHING CHARACTERISTICS FOR THE PAL20R8-5



t_{PD} vs. Number of Outputs Switching Vcc = 4.75 V, T_A = 75°C (Note 1) 16490C-20



t_{PD} vs. Load Capacitance V_{CC} = 5.0 V, T_A = 25°C

16490C-21

Note:

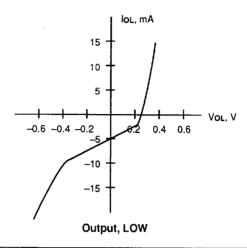
1. These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where tro may be affected.

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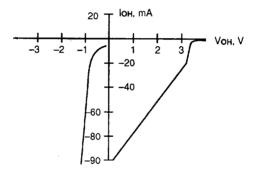
PAL20R8-5

CURRENT VS. VOLTAGE (I-V) CHARACTERISTICS FOR THE PAL20R8-5

 $Vcc = 5.0 \text{ V}, T_A = 25^{\circ}C$

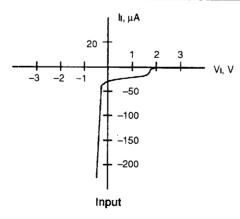


16490C-22



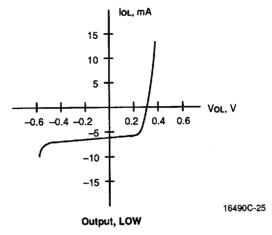
Output, HIGH

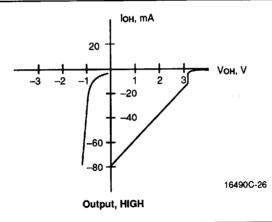
16490C-23

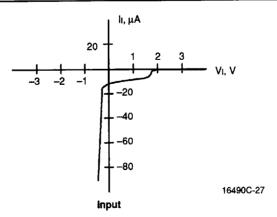


16490C-24

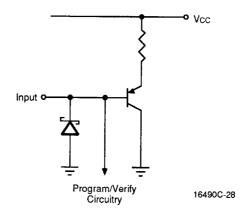
CURRENT VS. VOLTAGE (I-V) CHARACTERISTICS FOR THE PAL20R8-7/12 $V_{\rm CC}$ = 5.0 V, $T_{\rm A}$ = 25°C



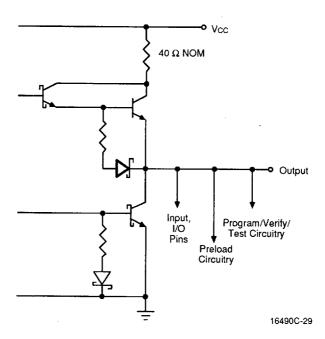




INPUT/OUTPUT EQUIVALENT SCHEMATICS



Typical Input



Typical Output



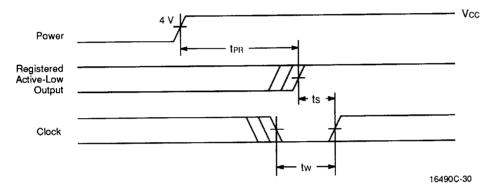
POWER-UP RESET

The power-up reset feature ensures that all flip-flops will be reset to LOW after the device has been powered up. The output state will be HIGH due to the inverting output buffer. This feature is valuable in simplifying state machine initialization. A timing diagram and parameter table are shown below. Due to the synchronous operation of the power-up reset and the wide range of ways Vcc

can rise to its steady state, two conditions are required to ensure a valid power-up reset. These conditions are:

- The Vcc rise must be monotonic.
- Following reset, the clock input must not be driven from LOW to HIGH until all applicable input and feedback setup times are met.

Parameter Symbol	Parameter Description	Max	Unit		
tpr	Power-Up Reset Time	1000	ns		
ts	Input or Feedback Setup Time	See Switching (See Switching Characteristics		
twL	Clock Width LOW	3			



Power-Up Reset Waveform



DATA SHEET REVISION SUMMARY FOR PAL20R8 Family

Current vs. Voltage (I-V) Characteristics Inserted PAL20R8-7/12 I-V curves